

این دیتاشیت توسط توکل الکترونیک تهیه و ارائه شده است.
جهت مشاهده قیمت، موجودی و ثبت سفارش این قطعه به وبسایت توکل الکترونیک مراجعه فرمایید.



مشاهده قیمت و خرید

برای خرید و مشاهده سایر محصولات کلیک کنید



2SK1317

Silicon N-Channel MOS FET

HITACHI

Application

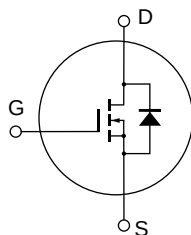
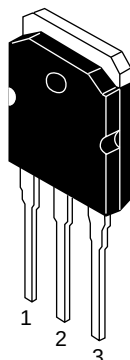
High speed power switching

Features

- High breakdown voltage $V_{DS} = 1500\text{ V}$
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for switching regulator, DC-DC converter and motor driver

Outline

TO-3P



1. Gate
2. Drain
(Flange)
3. Source

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	1500	V
Gate to source voltage	V_{GSS}	± 20	V
Drain current	I_D	2.5	A
Drain peak current	$I_{D(pulse)}^{*1}$	7	A
Body to drain diode reverse drain current	I_{DR}	2.5	A
Channel dissipation	P_{ch}^{*2}	100	W
Channel temperature	T_{ch}	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

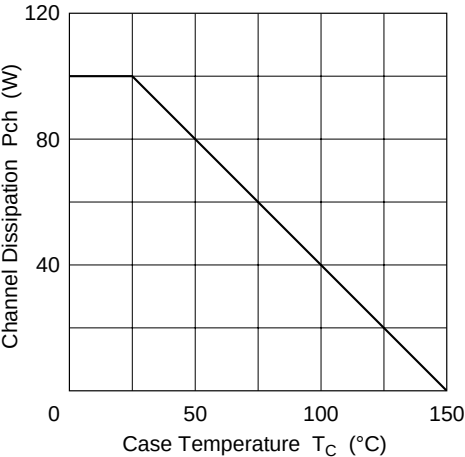
Notes: 1. $PW \leq 10 \mu s$, duty cycle $\leq 1\%$
2. Value at $T_c = 25^\circ C$

Electrical Characteristics (Ta = 25°C)

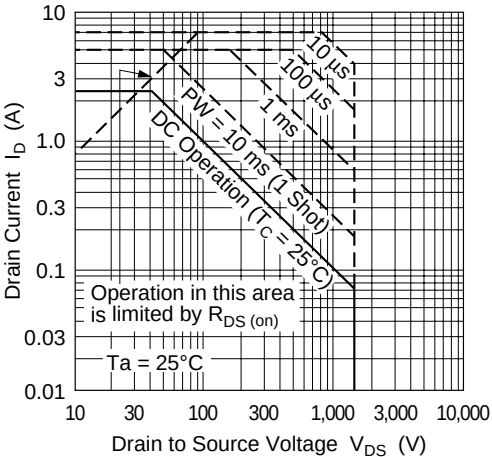
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	1500	—	—	V	$I_D = 10 \text{ mA}$, $V_{GS} = 0$
Gate to source leak current	I_{GSS}	—	—	± 1	μA	$V_{GS} = \pm 20 \text{ V}$, $V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	500	μA	$V_{DS} = 1200 \text{ V}$, $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	2.0	—	4.0	V	$I_D = 1 \text{ mA}$, $V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	$R_{DS(on)}$	—	9	12	Ω	$I_D = 2 \text{ A}$, $V_{GS} = 15 \text{ V}^{*1}$
Forward transfer admittance	$ y_{fs} $	0.45	0.75	—	S	$I_D = 1 \text{ A}$, $V_{DS} = 20 \text{ V}^{*1}$
Input capacitance	C_{iss}	—	990	—	pF	$V_{DS} = 10 \text{ V}$, $V_{GS} = 0$, $f = 1 \text{ MHz}$
Output capacitance	C_{oss}	—	125	—	pF	
Reverse transfer capacitance	C_{rss}	—	60	—	pF	
Turn-on delay time	$t_{d(on)}$	—	17	—	ns	$I_D = 2 \text{ A}$, $V_{GS} = 10 \text{ V}$, $R_L = 15 \Omega$
Rise time	t_r	—	70	—	ns	
Turn-off delay time	$t_{d(off)}$	—	110	—	ns	
Fall time	t_f	—	60	—	ns	
Body to drain diode forward voltage	V_{DF}	—	0.9	—	V	$I_F = 2 \text{ A}$, $V_{GS} = 0$
Body to drain diode reverse recovery time	t_{rr}	—	1750	—	ns	$I_F = 2 \text{ A}$, $V_{GS} = 0$, $di_F/dt = 100 \text{ A}/\mu s$

Note: 1. Pulse test

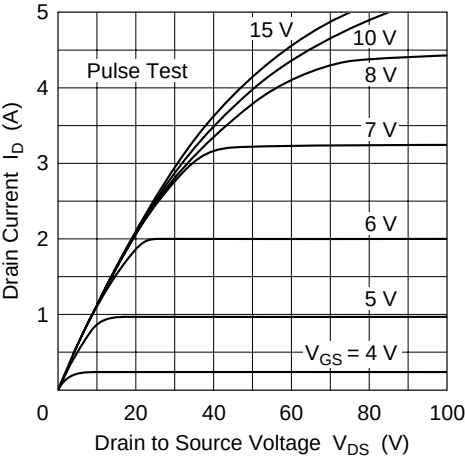
Power vs. Temperature Derating



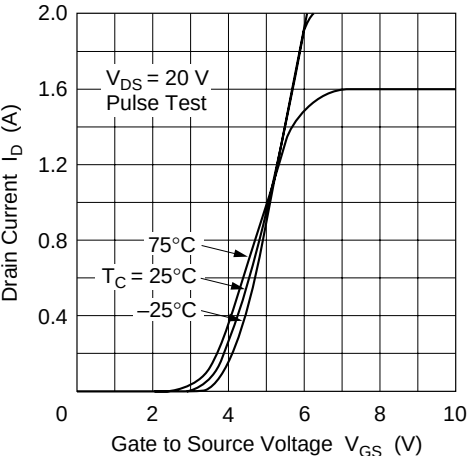
Maximum Safe Operation Area

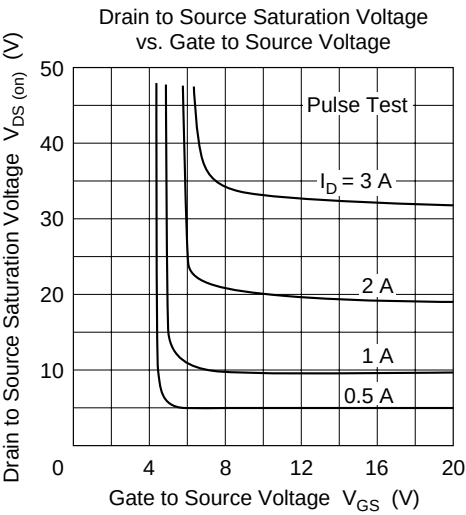
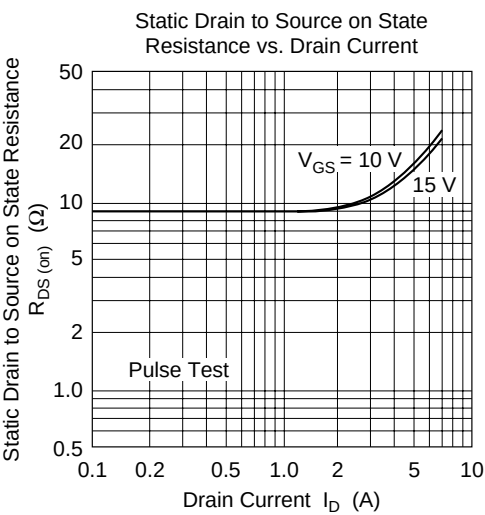
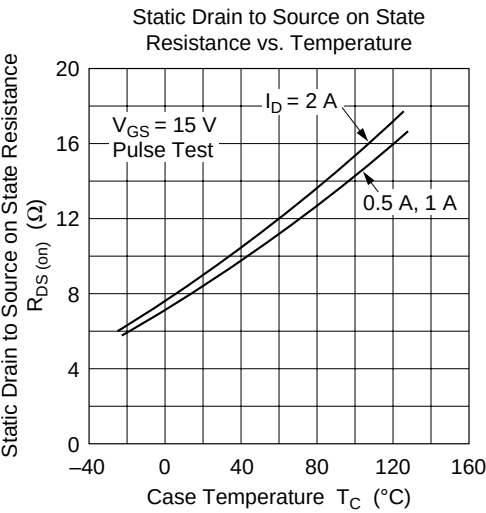
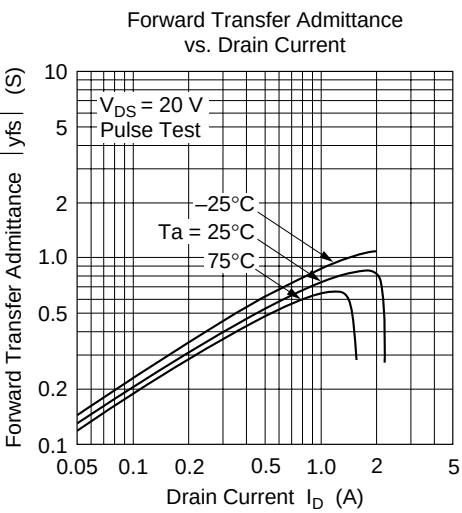


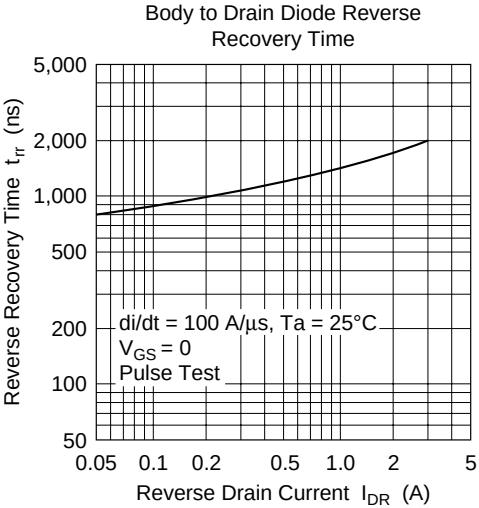
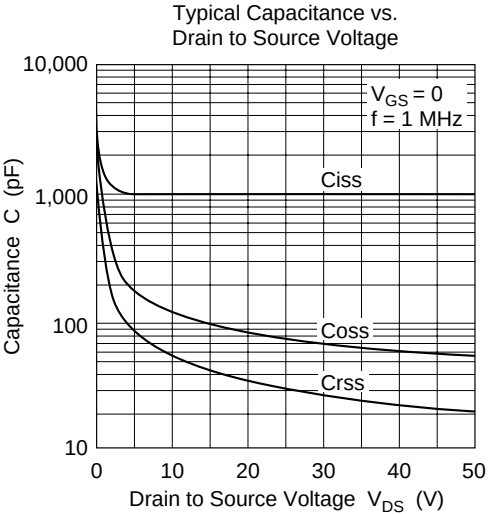
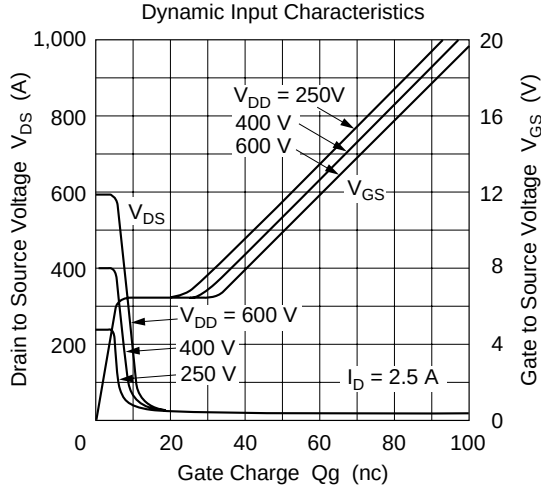
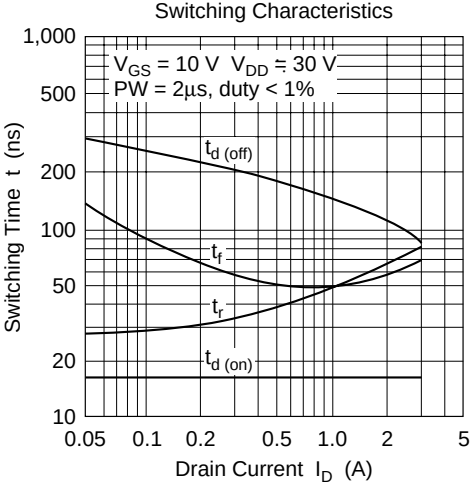
Typical Output Characteristics

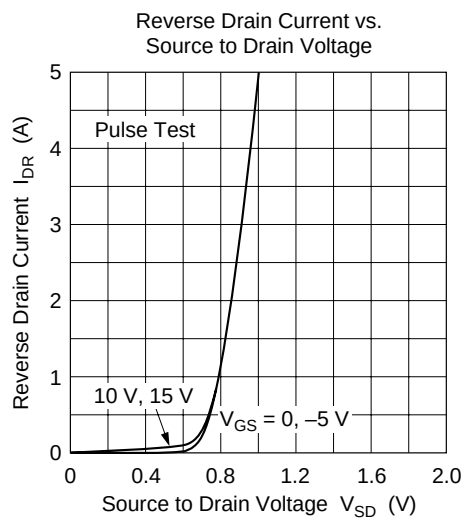
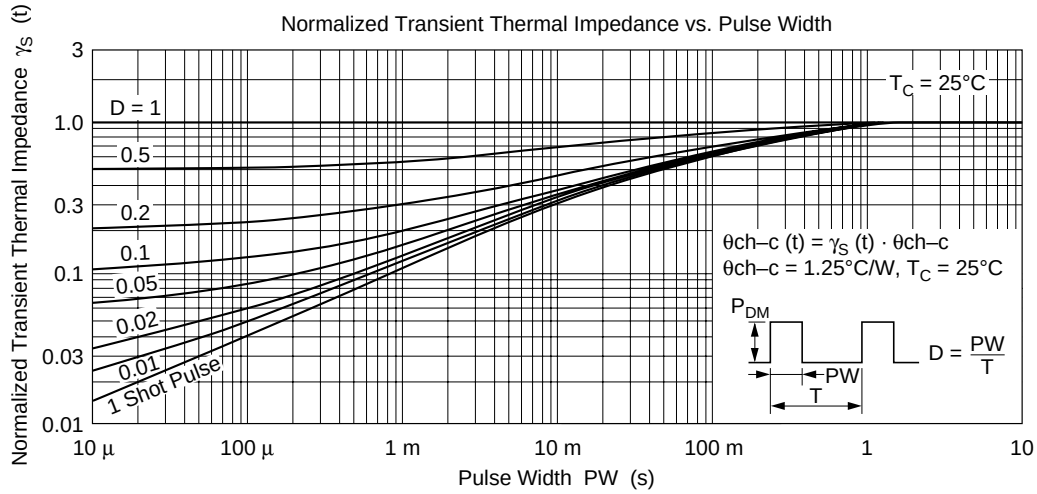
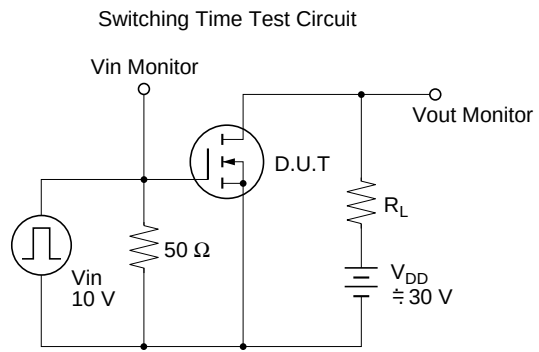
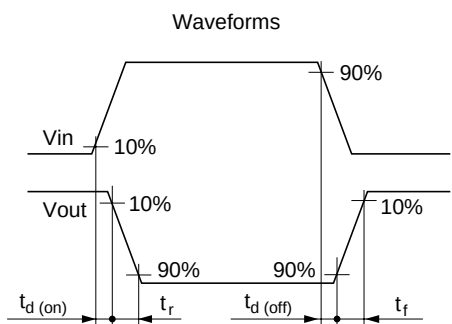


Typical Transfer Characteristics

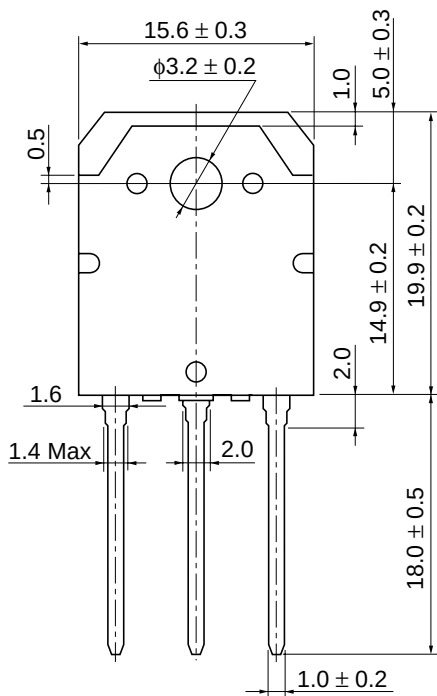
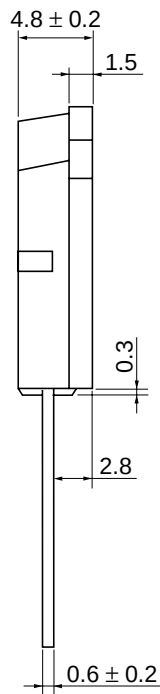
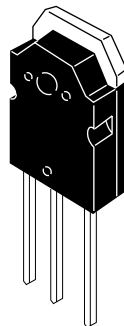
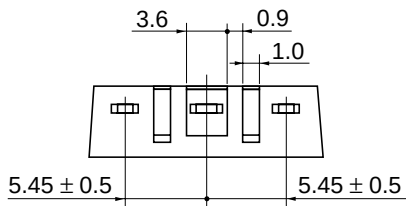








Unit: mm



Hitachi Code	TO-3P
JEDEC	—
EIAJ	Conforms
Weight (reference value)	5.0 g

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